

#### **Features**

- · Split Gate Trench Power MV MOSFET Technology
- · Low Gate Charge
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# **Maximum Ratings**

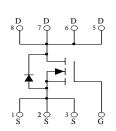
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Maximum Thermal Resistance: 40°C/W Junction to Ambient

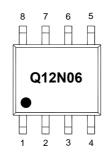
Parameter	Symbol	Rating	Unit
Drain -source Voltage	V <sub>DS</sub>	60	V
Gate -Source Voltage	$V_{GS}$	±20	V
Drain Current-Continuous	I <sub>D</sub>	12	Α
Drain Current-Pulse <sup>(Note 2)</sup>	I <sub>DM</sub>	48	Α
Power Dissipation	P <sub>D</sub>	3.1	W

#### Note:

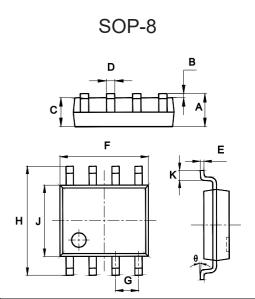
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine,
- <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. Repetitive rating; pulse width limited by max. junction temperature.

# **Internal Structure and Marking Code**



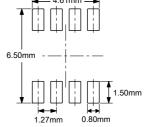


# N-Channel Power MOSFET



DIMENSIONS						
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.053	0.069	1.35	1.75		
В	0.004	0.010	0.10	0.25		
С	0.053	0.061	1.35	1.55		
D	0.013	0.020	0.33	0.51		
Е	0.007	0.010	0.17	0.25		
F	0.185	0.200	4.70	5.10		
G	0.0	0.050		270	TYP.	
Н	0.228	0.244	5.80	6.20		
J	0.150	0.157	3.80	4.00		
K	0.016	0.050	0.40	1.27		
θ	0°	8°	0°	8°		





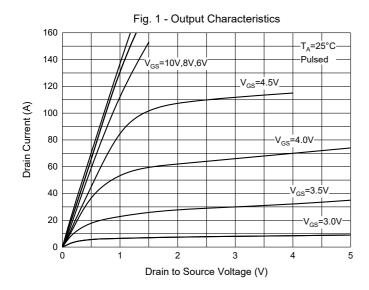


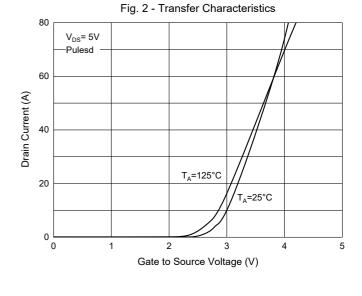
# ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

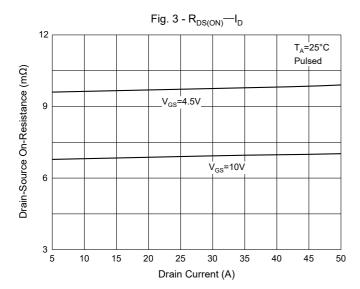
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Static Characteristics							
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	60	65		V	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.1	1.7	2.5	V	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V			1 5	μA	
Drain-Source On-Resistance	R <sub>DS(on)</sub>	$V_{GS}$ =10V, $I_{D}$ =12A $V_{GS}$ =4.5V, $I_{D}$ =12A		8.2 10.5	9.0 13	mΩ	
Forward Tranconductance	g <sub>FS</sub>	V <sub>DS</sub> =5V, I <sub>D</sub> =12A	30			S	
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =12A		0.83	0.99	V	
Maximum Body-Diode Continuous Current	Is				12	Α	
Dynamic Characteristics							
Input Capacitance	C <sub>iss</sub>			1988		pF	
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V, f=1MHz		470			
Reverse Transfer Capacitance	C <sub>rss</sub>			14			
Gate Resistance	$R_g$	V <sub>DS</sub> =0V,V <sub>GS</sub> =0V, f=1MHz		1.6		Ω	
Switching Characteristics							
Turn-On Delay Time	t <sub>d(on)</sub>			10.5			
Turn-On Rise Time	t <sub>r</sub>	V <sub>GS</sub> =10V,V <sub>DS</sub> =15V,		4.5		- ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_{GEN}$ =3 $\Omega$ , $R_L$ =2.5 $\Omega$		29.5			
Turn-Off Fall Time	t <sub>f</sub>			8.0			
Total Gate Charge(10V)	0			31			
Total Gate Charge(4.5V)	$Q_g$			16		nC	
Gate-Source Chage	Q <sub>gs</sub>	V <sub>GS</sub> =10V, V <sub>DS</sub> =30V, I <sub>D</sub> =12A		6.0			
Gage-Drain Charge	$Q_{gd}$			5.0			
Body Diode Reverse Recovery Time	t <sub>rr</sub>	1 -12A di/dt-500A/va		17		ns	
Body Diode Reverse Recovery charge	Q <sub>rr</sub>	I <sub>F</sub> =12A,di/dt=500A/μs		58		nC	

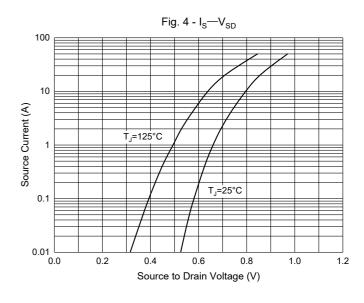


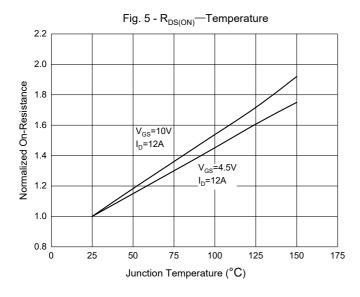
#### **Curve Characteristics**

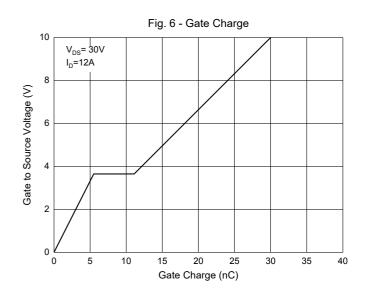






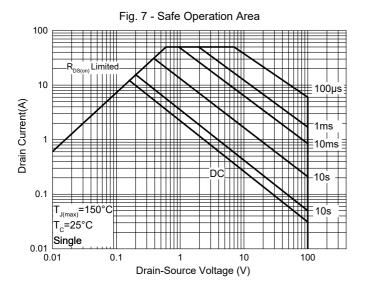








# **Curve Characteristics**





# **Ordering Information**

Device	Packing	
Part Number-TP	Tape&Reel:4Kpcs/Reel	

## \*\*\*IMPORTANT NOTICE\*\*\*

**Micro Commercial Components Corp.** reserves the right to make changes without further notice to any product herein to make corrections, modifications, enhancements, improvements, or other changes. **Micro Commercial Components Corp**. does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold **Micro Commercial Components Corp**, and all the companies whose products are represented on our website, harmless against all damages. **Micro Commercial Components Corp**, products are sold subject to the general terms and conditions of commercial sale, as published at

#### https://www.mccsemi.com/Home/TermsAndConditions.

### \*\*\*LIFE SUPPORT\*\*\*

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

#### \*\*\*CUSTOMER AWARENESS\*\*\*

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.